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# FCD600N60Z

## N-Channel SuperFET® II MOSFET

### 600 V, 7.4 A, 600 mΩ

#### Features

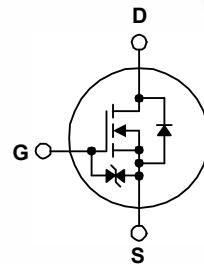
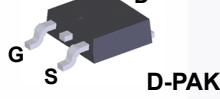
- 650 V @  $T_J = 150^\circ\text{C}$
- Typ.  $R_{DS(on)} = 510 \text{ m}\Omega$
- Ultra Low Gate Charge (Typ.  $Q_g = 20 \text{ nC}$ )
- Low Effective Output Capacitance (Typ.  $C_{oss(\text{eff.})} = 74 \text{ pF}$ )
- 100% Avalanche Tested
- ESD Improved Capacity
- RoHS Compliant

#### Applications

- LCD / LED / PDP TV and Monitor Lighting
- Solar Inverter
- AC-DC Power Supply

#### Description

SuperFET® II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET II MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications.



**Absolute Maximum Ratings**  $T_C = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter		FCD600N60Z	Unit
$V_{DSS}$	Drain to Source Voltage		600	V
$V_{GSS}$	Gate to Source Voltage		$\pm 20$	V
	- AC ( $f > 1 \text{ Hz}$ )		$\pm 30$	V
$I_D$	Drain Current		7.4	A
	- Continuous ( $T_C = 100^\circ\text{C}$ )		4.7	
$I_{DM}$	Drain Current		22.2	A
$E_{AS}$	Single Pulsed Avalanche Energy		135	mJ
$I_{AR}$	Avalanche Current		1.5	A
$E_{AR}$	Repetitive Avalanche Energy		0.89	mJ
$dv/dt$	MOSFET $dv/dt$		100	V/ns
	Peak Diode Recovery $dv/dt$		20	
$P_D$	Power Dissipation ( $T_C = 25^\circ\text{C}$ )		89	W
	- Derate Above $25^\circ\text{C}$		0.71	$\text{W}/^\circ\text{C}$
$T_J, T_{STG}$	Operating and Storage Temperature Range		-55 to +150	$^\circ\text{C}$
$T_L$	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	$^\circ\text{C}$

#### Thermal Characteristics

Symbol	Parameter	FCD600N60Z	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	1.4	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	100	

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FCD600N60Z	FCD600N60Z	DPAK	Tape and Reel	330 mm	16 mm	2500 units

## Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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### Off Characteristics

$\text{BV}_{\text{DSS}}$	Drain to Source Breakdown Voltage	$V_{\text{GS}} = 0 \text{ V}$ , $I_D = 10 \text{ mA}$ , $T_J = 25^\circ\text{C}$	600	-	-	V
		$V_{\text{GS}} = 0 \text{ V}$ , $I_D = 10 \text{ mA}$ , $T_J = 150^\circ\text{C}$	650	-	-	
$\Delta \text{BV}_{\text{DSS}} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 10 \text{ mA}$ , Referenced to $25^\circ\text{C}$	-	0.67	-	$\text{V}^\circ\text{C}$
$\text{BV}_{\text{DS}}$	Drain to Source Avalanche Breakdown Voltage	$V_{\text{GS}} = 0 \text{ V}$ , $I_D = 7.4 \text{ A}$	-	700	-	V
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{\text{DS}} = 480 \text{ V}$ , $V_{\text{GS}} = 0 \text{ V}$	-	-	5	$\mu\text{A}$
		$V_{\text{DS}} = 480 \text{ V}$ , $T_C = 125^\circ\text{C}$	-	-	20	
$I_{\text{GSS}}$	Gate-Body Leakage Current	$V_{\text{GS}} = \pm 20 \text{ V}$ , $V_{\text{DS}} = 0 \text{ V}$	-	-	$\pm 10$	$\text{uA}$

### On Characteristics

$V_{\text{GS(th)}}$	Gate Threshold Voltage	$V_{\text{GS}} = V_{\text{DS}}$ , $I_D = 250 \mu\text{A}$	2.5	-	3.5	V
$R_{\text{DS(on)}}$	Static Drain to Source On Resistance	$V_{\text{GS}} = 10 \text{ V}$ , $I_D = 3.7 \text{ A}$	-	0.51	0.6	$\Omega$
$g_{\text{FS}}$	Forward Transconductance	$V_{\text{DS}} = 20 \text{ V}$ , $I_D = 3.7 \text{ A}$	-	6.7	-	S

### Dynamic Characteristics

$C_{\text{iss}}$	Input Capacitance	$V_{\text{DS}} = 25 \text{ V}$ , $V_{\text{GS}} = 0 \text{ V}$ , $f = 1 \text{ MHz}$	-	840	1120	pF
$C_{\text{oss}}$	Output Capacitance		-	630	840	pF
$C_{\text{rss}}$	Reverse Transfer Capacitance		-	30	45	pF
$C_{\text{oss}}$	Output Capacitance	$V_{\text{DS}} = 380 \text{ V}$ , $V_{\text{GS}} = 0 \text{ V}$ , $f = 1 \text{ MHz}$	-	16.5	-	pF
$C_{\text{oss(eff.)}}$	Effective Output Capacitance	$V_{\text{DS}} = 0 \text{ V}$ to $480 \text{ V}$ , $V_{\text{GS}} = 0 \text{ V}$	-	74	-	pF
$Q_{\text{g(tot)}}$	Total Gate Charge at 10V	$V_{\text{DS}} = 380 \text{ V}$ , $I_D = 3.7 \text{ A}$ , $V_{\text{GS}} = 10 \text{ V}$	-	20	26	nC
$Q_{\text{gs}}$	Gate to Source Gate Charge	(Note 4)	-	3.4	-	nC
$Q_{\text{gd}}$	Gate to Drain "Miller" Charge		-	7.5	-	nC
ESR	Equivalent Series Resistance	$f = 1 \text{ MHz}$	-	2.89	-	$\Omega$

### Switching Characteristics

$t_{\text{d(on)}}$	Turn-On Delay Time	$V_{\text{DD}} = 380 \text{ V}$ , $I_D = 3.7 \text{ A}$ , $V_{\text{GS}} = 10 \text{ V}$ , $R_G = 4.7 \Omega$	-	13	36	ns
$t_r$	Turn-On Rise Time		-	7	24	ns
$t_{\text{d(off)}}$	Turn-Off Delay Time		-	39	88	ns
$t_f$	Turn-Off Fall Time		(Note 4)	-	9	28

### Drain-Source Diode Characteristics

$I_S$	Maximum Continuous Drain to Source Diode Forward Current	-	-	7.4	A	
$I_{\text{SM}}$	Maximum Pulsed Drain to Source Diode Forward Current	-	-	22.2	A	
$V_{\text{SD}}$	Drain to Source Diode Forward Voltage	$V_{\text{GS}} = 0 \text{ V}$ , $I_{\text{SD}} = 3.7 \text{ A}$	-	-	1.2	V
$t_{\text{rr}}$	Reverse Recovery Time	$V_{\text{GS}} = 0 \text{ V}$ , $I_{\text{SD}} = 3.7 \text{ A}$ , $dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	200	-	ns
$Q_{\text{rr}}$	Reverse Recovery Charge	-	2.3	-	$\mu\text{C}$	

#### Notes:

1. Repetitive rating: pulse-width limited by maximum junction temperature.
2.  $I_{\text{AS}} = 1.5 \text{ A}$ ,  $V_{\text{DD}} = 50 \text{ V}$ ,  $R_G = 25 \Omega$ , starting  $T_J = 25^\circ\text{C}$ .
3.  $I_{\text{SD}} \leq 3.7 \text{ A}$ ,  $di/dt \leq 200 \text{ A}/\mu\text{s}$ ,  $V_{\text{DD}} \leq \text{BV}_{\text{DSS}}$ , starting  $T_J = 25^\circ\text{C}$ .
4. Essentially independent of operating temperature typical characteristics.

## Typical Performance Characteristics

Figure 1. On-Region Characteristics

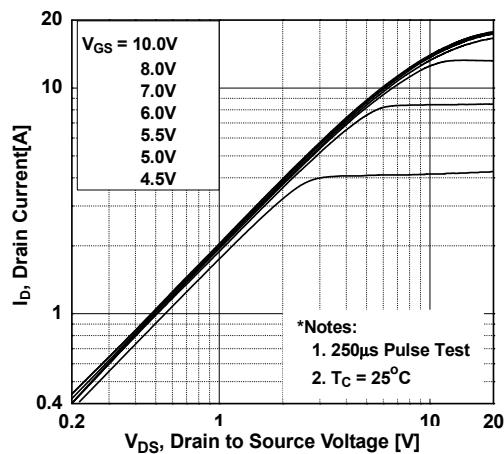


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

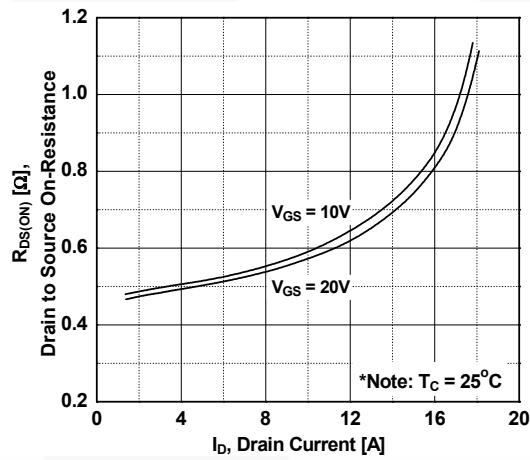


Figure 5. Capacitance Characteristics

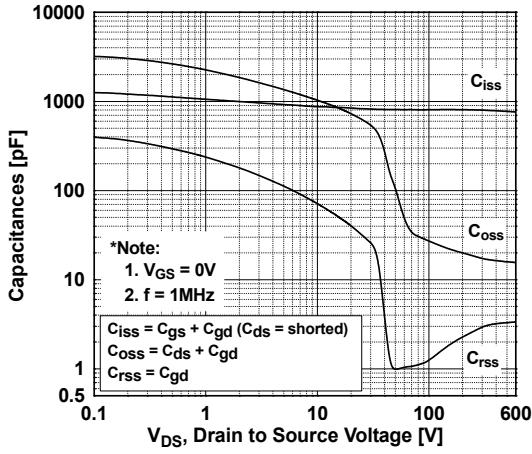


Figure 2. Transfer Characteristics

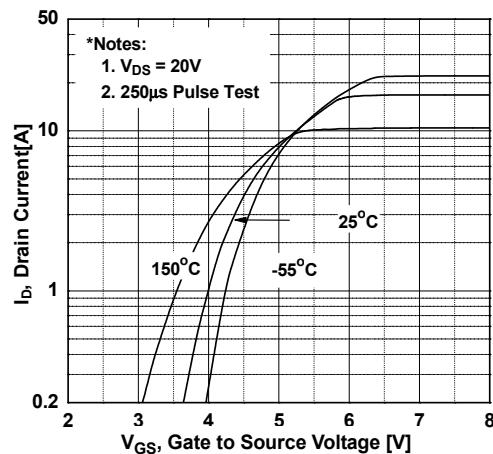


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

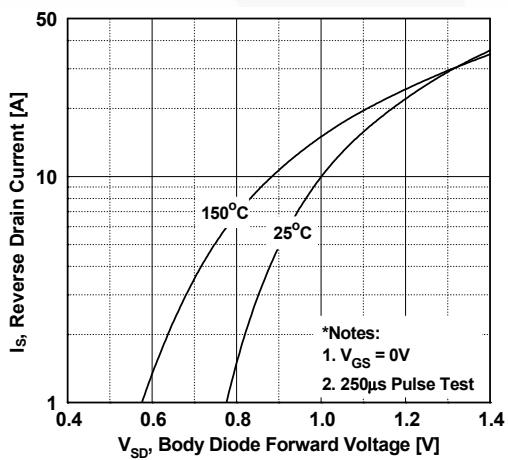
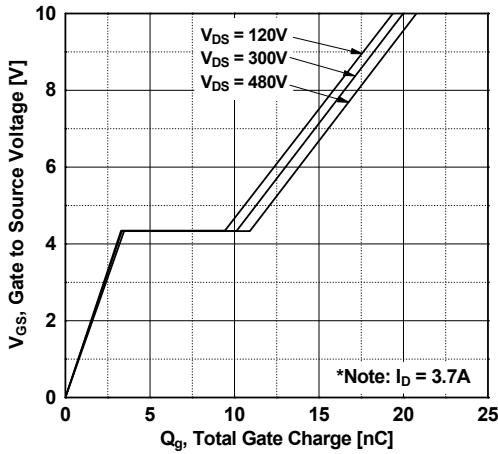
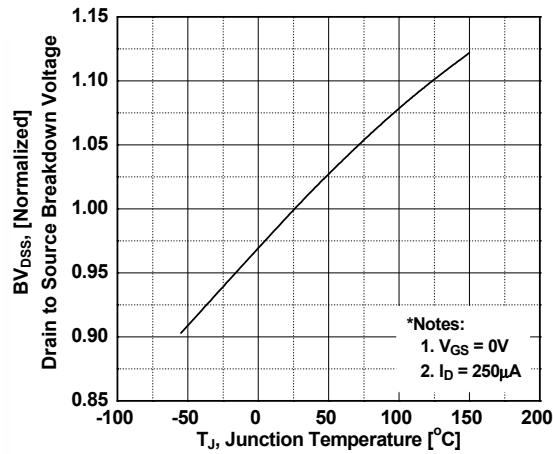


Figure 6. Gate Charge Characteristics

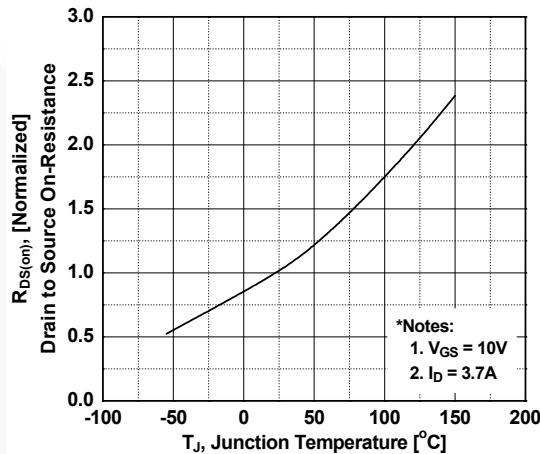


## Typical Performance Characteristics (Continued)

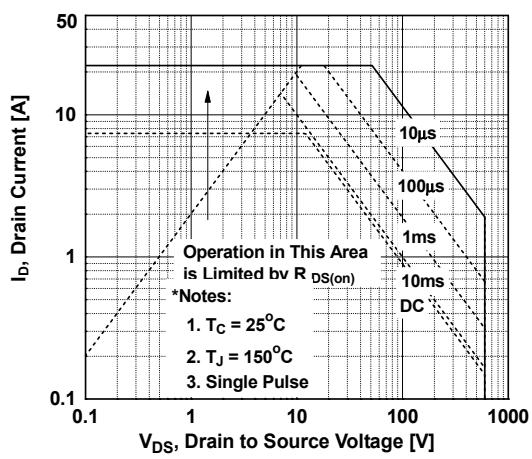
**Figure 7. Breakdown Voltage Variation vs. Temperature**



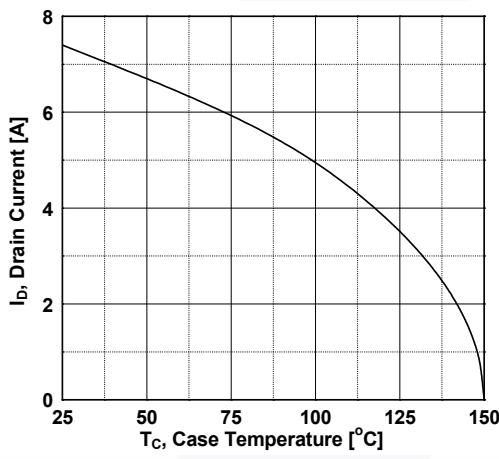
**Figure 8. On-Resistance Variation vs. Temperature**



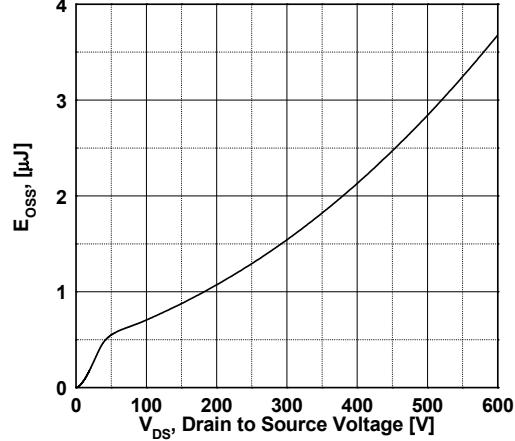
**Figure 9. Maximum Safe Operating Area**



**Figure 10. Maximum Drain Current vs. Case Temperature**

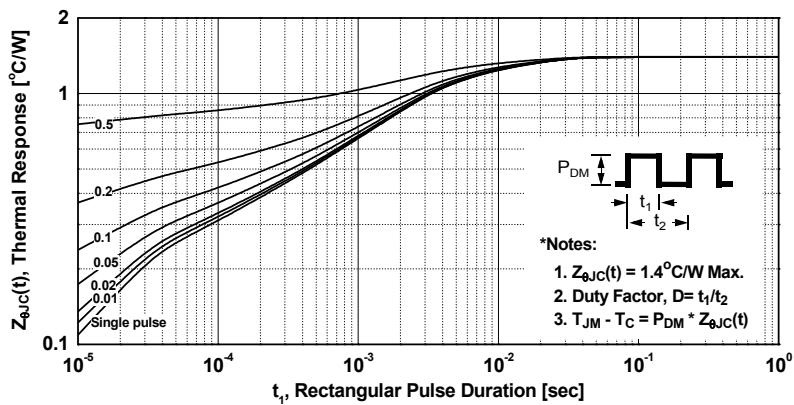


**Figure 11. Eoss vs. Drain to Source Voltage**



## Typical Performance Characteristics (Continued)

Figure 12. Transient Thermal Response Curve



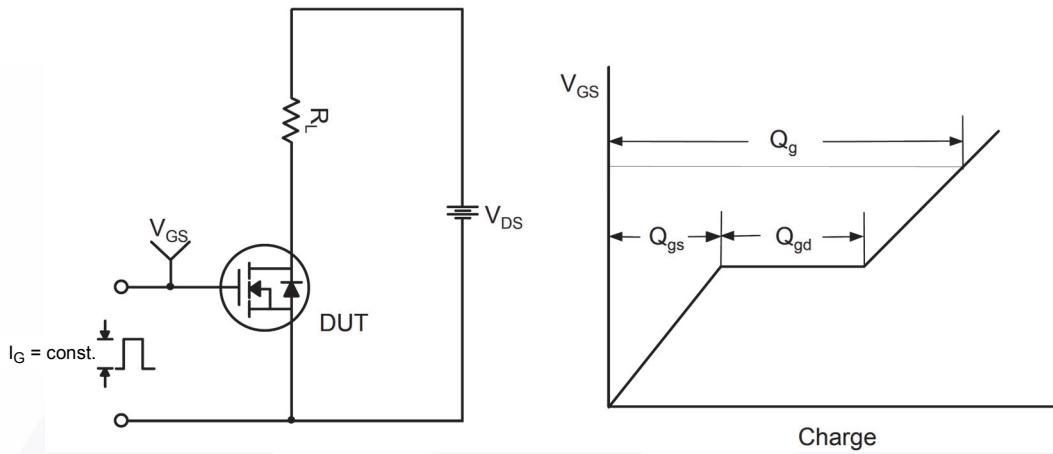


Figure 13. Gate Charge Test Circuit & Waveform

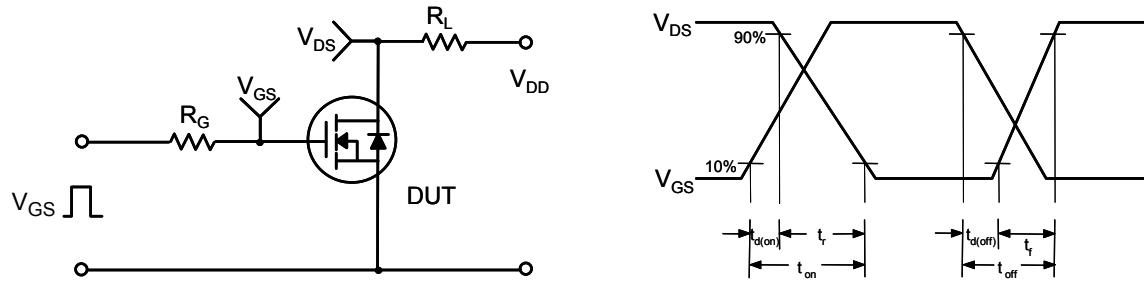


Figure 14. Resistive Switching Test Circuit & Waveforms

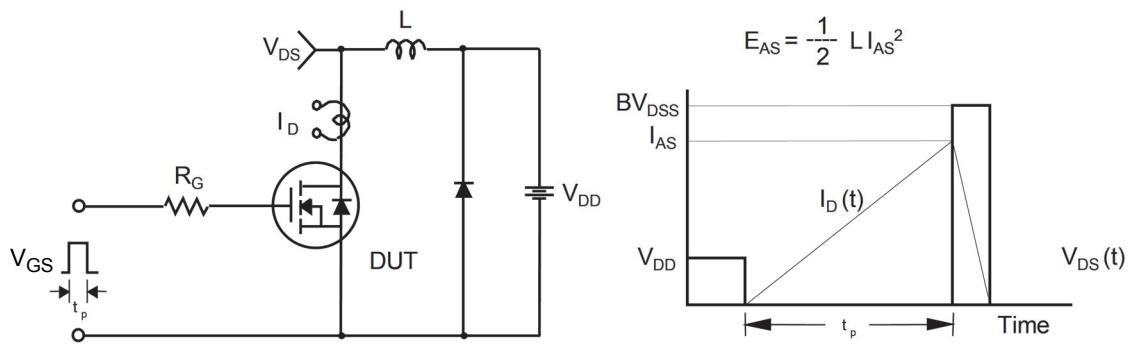


Figure 15. Unclamped Inductive Switching Test Circuit & Waveforms

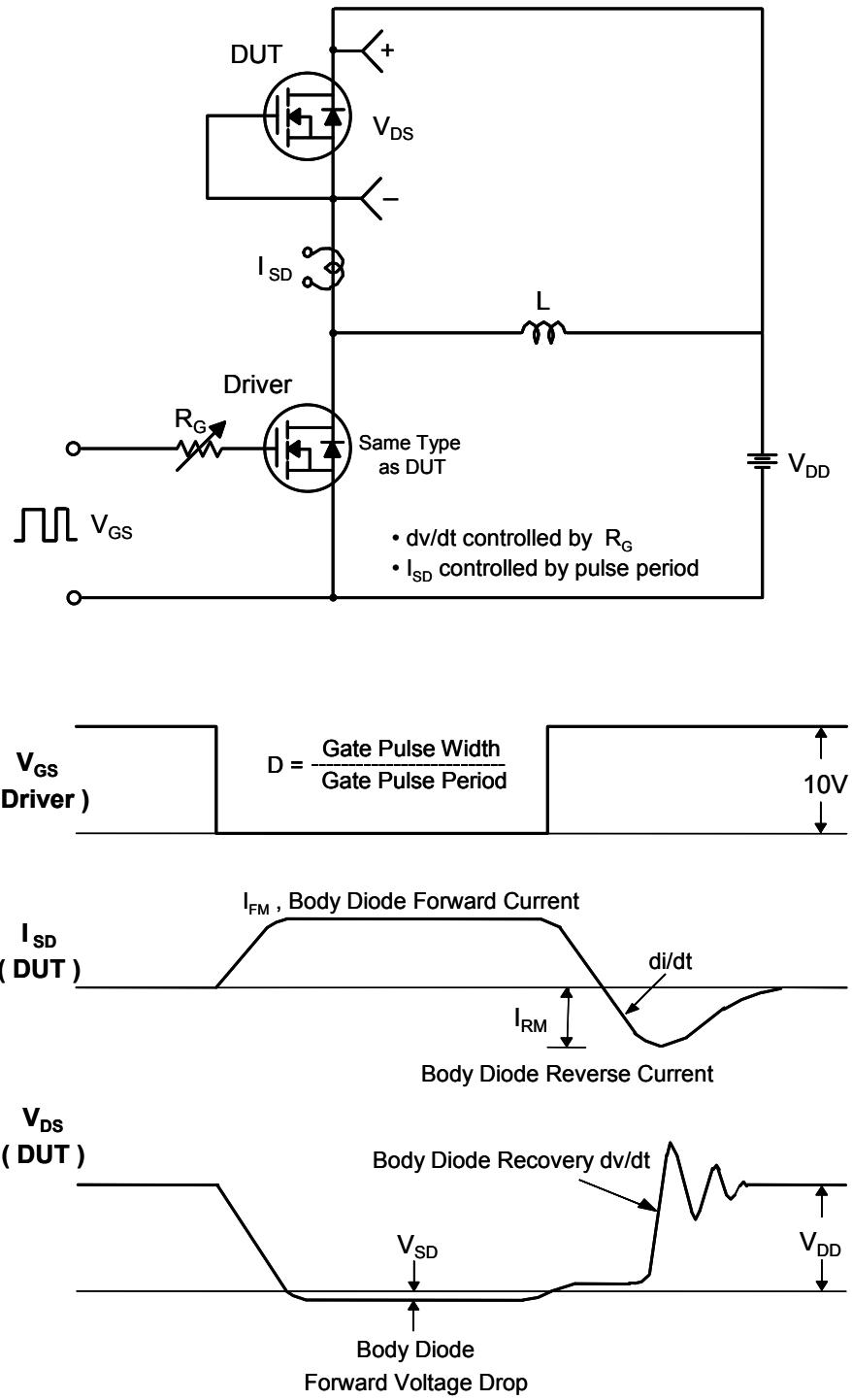


Figure 16. Peak Diode Recovery  $dv/dt$  Test Circuit & Waveforms

## Mechanical Dimensions

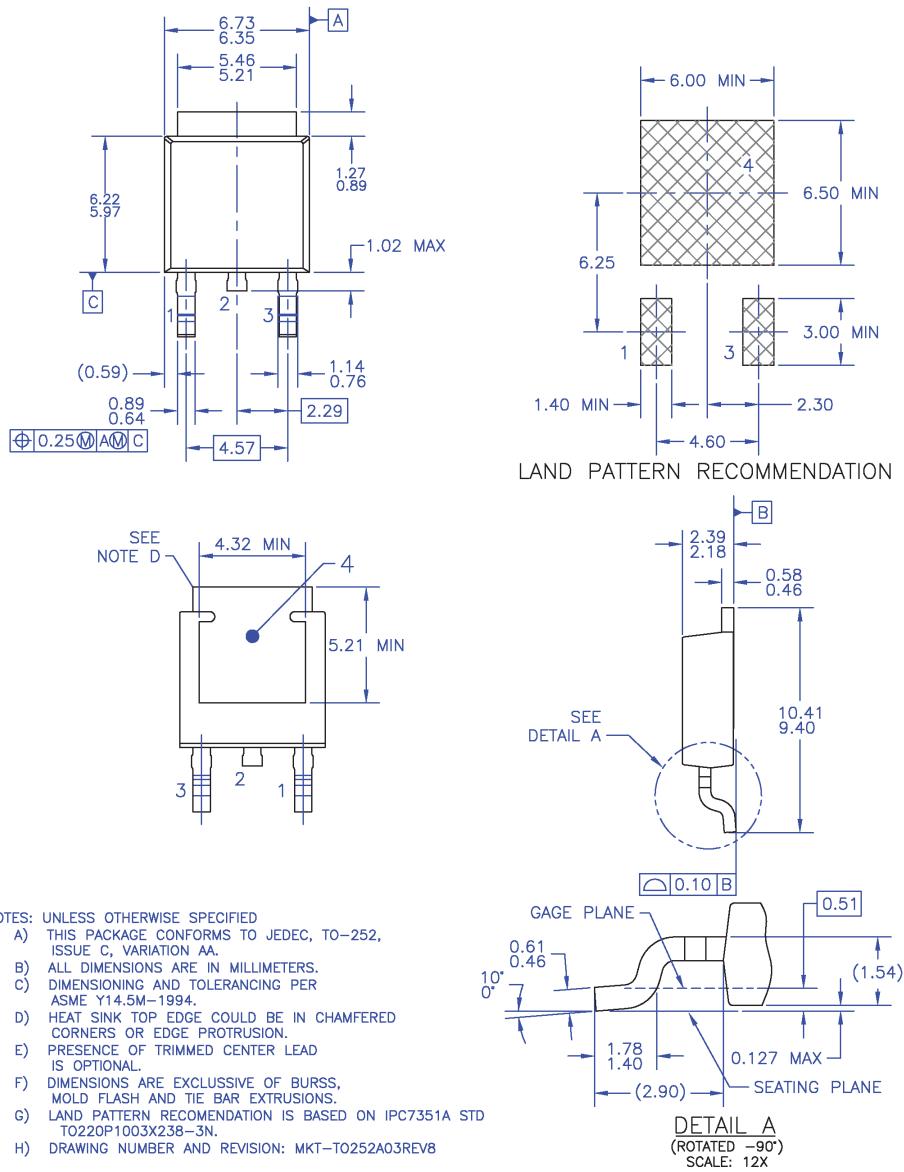


Figure 17. TO252 (D-PAK), Molded, 3-Lead, Option AA&AB

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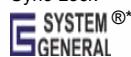
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